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## FDD6688/FDU6688 30V N-Channel PowerTrench<sup>o</sup> MOSFET

### **General Description**

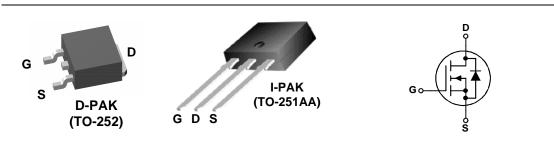
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low RDS( ON) and fast switching speed.

### Applications

- DC/DC converter
- Motor Drives

### Features

- 84 A, 30 V.  $R_{DS(ON)} = 5 \ m\Omega \ @ \ V_{GS} = 10 \ V$  $R_{DS(ON)} = 6 \ m\Omega \ @ \ V_{GS} = 4.5 \ V$
- Low gate charge
- Fast switching
- High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$



### Absolute Maximum Ratings T<sub>A=25°C</sub> unless otherwise noted

Symbo I	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		30	V
V <sub>GSS</sub>	Gate-Source Voltage		±20	
I <sub>D</sub>	Drain Current – Continuous	(Note 3)	84	A
	– Pulsed	(Note 1a)	100	
P <sub>D</sub>	Power Dissipation for Single Operation	(Note 1)	83	W
		(Note 1a)	3.8	
		(Note 1b)	1.6	
$T_{J}, T_{STG}$	Operating and Storage Junction Temperature Range		-55 to +175	°C

### **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	1.8	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	40	
		(Note 1b)	96	

### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape width	Quantity
FDD6688	FDD6688	D-PAK (TO-252)	13"	16mm	2500 units
FDU6688	FDU6688	I-PAK (TO-251)	Tube	N/A	75

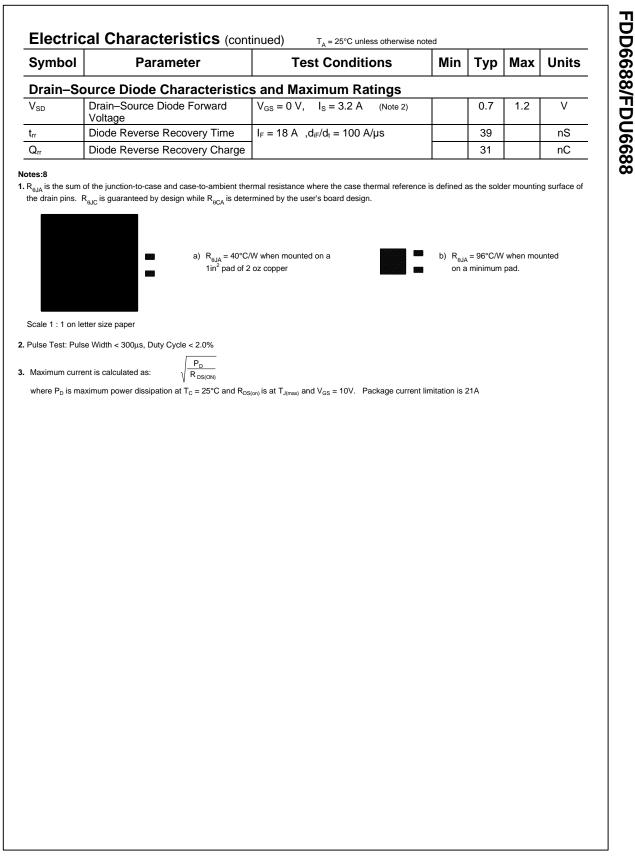
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## FDD6688/FDU6688

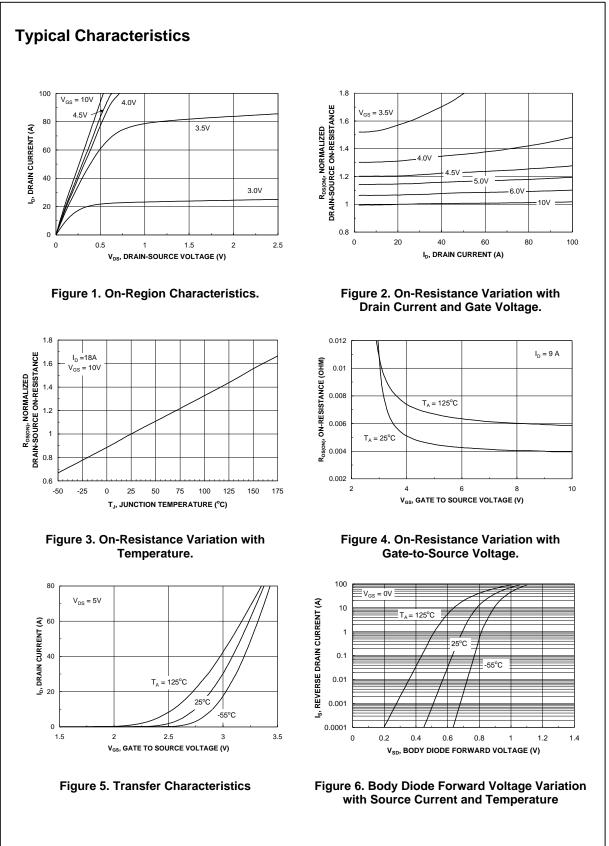
March 2015

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	burce Avalanche Ratings (No	ote 2)				
W <sub>DSS</sub>	Drain-Source Avalanche Energy	Single Pulse, $V_{DD} = 15 \text{ V}$ , $I_D = 21 \text{ A}$			370	mJ
I <sub>AR</sub>	Drain-Source Avalanche Current				21	А
Off Char	acteristics					
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \qquad I_D = 250 \mu\text{A}$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		24		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 24 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			1	μA
I <sub>GSS</sub>	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	1	1.8	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C		-5		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance			4 5 6	5 6 10	mΩ
I <sub>D(on)</sub>	On–State Drain Current	$V_{GS} = 10 \text{ V},  V_{DS} = 5 \text{ V}$	50			А
<b>g</b> <sub>FS</sub>	Forward Transconductance	$V_{DS} = 5 V$ , $I_D = 18 A$		88		S
Dynamic	Characteristics				1	
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 15 V$ , $V_{GS} = 0 V$ ,		3845		pF
Coss	Output Capacitance	f = 1.0 MHz		930		pF
Crss	Reverse Transfer Capacitance			368		pF
R <sub>G</sub>	Gate Resistance	$V_{GS} = 15 \text{ mV}, \text{ f} = 1.0 \text{ MHz}$		1.2		Ω
Switchin	g Characteristics (Note 2)			1		
t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = 15 V$ , $I_D = 1 A$ ,		15	27	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{GS} = 10 \text{ V},  R_{GEN} = 6 \Omega$		13	23	ns
t <sub>d(off)</sub>	Turn-Off Delay Time			62	99	ns
t <sub>f</sub>	Turn–Off Fall Time			36	58	ns
Q <sub>g</sub>	Total Gate Charge	$V_{DS} = 15V$ , $I_D = 18$ A,		37	56	nC
Q <sub>gs</sub>	Gate–Source Charge	$V_{GS} = 5 V$		10		nC
Q <sub>gd</sub>	Gate–Drain Charge	1		14		nC

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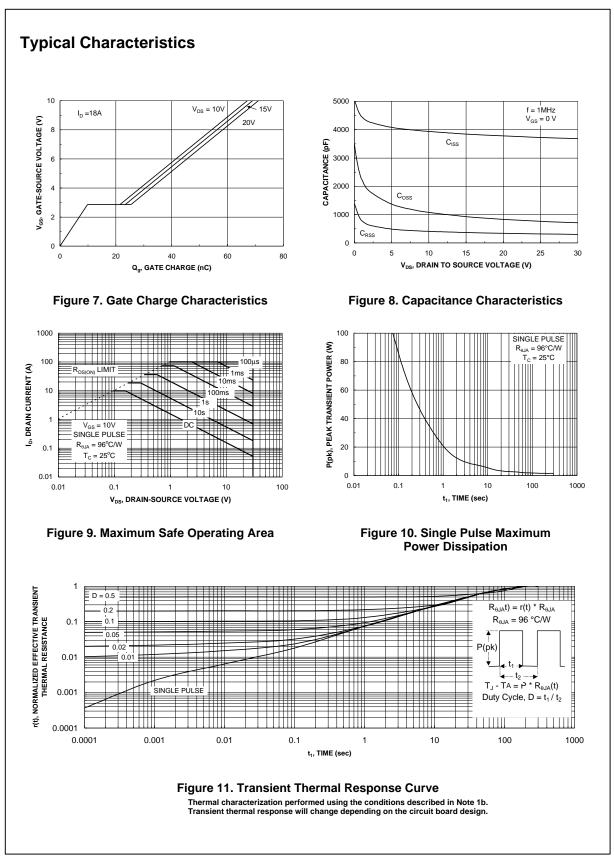


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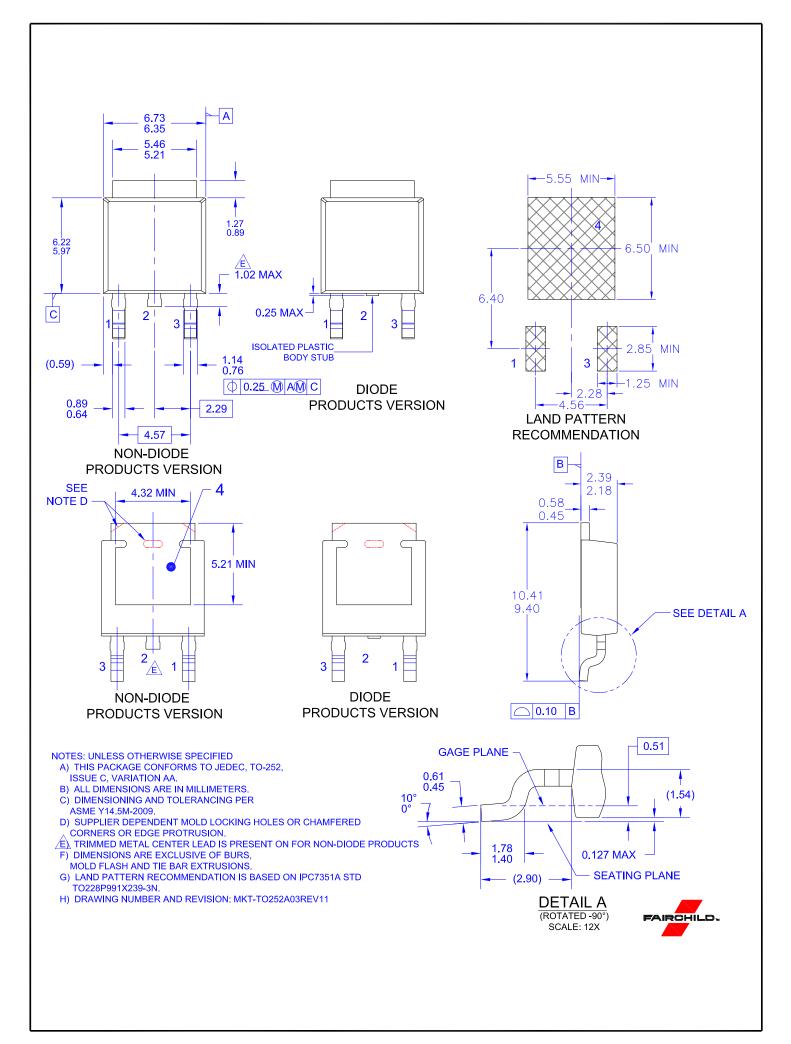
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